ACPL-267XL, ACPL-268KL, ACPL-560XL, ACPL-563XL, 5962-08242*



Hermetically Sealed, 3.3V High Speed, High CMR, Logic Gate Optocouplers

Data Sheet

*See Selection Guide for full matrix of part numbers.

Description

These units are single and dual channel, hermetically sealed optocouplers. The products are capable of operation and storage over the full military temperature range and can be purchased as either standard commercial product or with full MIL-PRF-38534 Class Level H or K testing or from DLA Drawing 5962-08242. All devices are manufactured and tested on a MIL-PRF-38534 certified line and are included in the DLA Qualified Manufacturers List QML-38534 for Hybrid Microcircuits.

Truth Table (Positive Logic)

Multichannel Devices

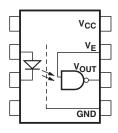
Input	Output
On (H)	L
Off (L)	Н

Single Channel DIP

Input	Enable	Output
On (H)	Н	L
Off (L)	Н	Н
On (H)	L	Н
Off (L)	L	Н

Functional Diagram

Multiple channel devices available



Features

- Low power consumption
- 3.3V supply voltages
- Dual marked with device part number and DLA drawing number
- Manufactured and tested on a MIL-PRF-38534 Certified Line
- QML-38534, Class H and K
- Three hermetically sealed package configurations
- Performance guaranteed over full military temperature range: -55°C to +125°C
- High speed: 10 Mbd typical
- CMR: > 10,000 V/µs typical
- 1500 Vdc withstand test voltage
- TTL circuit compatibility
- HCPL-260L/060L/263L/063L function compatibility

Applications

- Military and aerospace
- High reliability systems
- Transportation, medical, and life critical systems
- Line receiver
- Voltage level shifting
- Isolated input line receiver
- Isolated output line driver
- Logic ground isolation
- Harsh industrial environments
- Isolation for computer, communication, and test equipment systems

The connection of a 0.1 μ F bypass capacitor between V_{cc} and GND is recommended.

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

Each channel contains a GaAsP light emitting diode which is optically coupled to an integrated high speed photon detector. The output of the detector is an open collector Schottky clamped transistor. Internal shields provide a guaranteed common mode transient immunity specification of 1000 V/µs. Package styles for these parts are 8 and 16 pin DIP through hole (case outlines P and E respectively). Devices may be purchased with a variety of lead bend and plating options. See Selection Guide Table for details. Standard Microcircuit Drawing (SMD) parts are available for each package and lead style.

Because the same electrical die (emitters and detectors) are used for each channel of each device listed in this data sheet, absolute maximum ratings, recommended operating conditions, electrical specifications, and performance characteristics shown in the figures are identical for all parts. Occasional exceptions exist due to package variations and limitations, and are as noted. Additionally, the same package assembly processes and materials are used in all devices.

Selection Guide – Package Styles and Lead Configuration Options

Package	16 Pin DIP	8 Pin DIP	8 Pin DIP
Lead Style	Through Hole	Through Hole	Through Hole
Channels	2	1	2
Common Channel Wiring	VCC, GND	None	VCC, GND
Withstand Test Voltage	1500 Vdc	1500 Vdc	1500 Vdc
Avago Part # & Options			
Standard Commercial	ACPL-2670L	ACPL-5600L	ACPL-5630L
MIL-PRF-38534, Class H	ACPL-2672L	ACPL-5601L	ACPL-5631L
MIL-PRF-38534, Class K	ACPL-268KL	ACPL-560KL	ACPL-563KL
Standard Lead Finish	Gold Plate	Gold Plate	Gold Plate
Solder Dipped*	Option -200	Option -200	Option -200
Butt Cut/Gold Plate	Option -100	Option -100	Option -100
Gull Wing/Soldered*	Option -300	Option -300	Option -300
Class H SMD Part #			
Prescript for all below	5962-	5962-	5962-
Gold Plate	0824203HEC	0824201HPC	0824202HPC
Solder Dipped*	0824203HEA	0824201HPA	0824202HPA
Butt Cut/Gold Plate	0824203HUC	0824201HYC	0824202HYC
Butt Cut/Soldered*	0824203HUA	0824201HYA	0824202HYA
Gull Wing/Soldered*	0824203HTA	0824201HXA	0824202HXA
Class K SMD Part #			
Prescript for all below	5962-	5962-	5962-
Gold Plate	0824203KEC	0824201KPC	0824202KPC
Solder Dipped*	0824203KEA	0824201KPA	0824202KPA
Butt Cut/Gold Plate	0824203KUC	0824201KYC	0824202KYC
Butt Cut/Soldered*	0824203KUA	0824201KYA	0824202KYA
Gull Wing/Soldered*	0824203KTA	0824201KXA	0824202KXA

^{*} Solder contains lead.

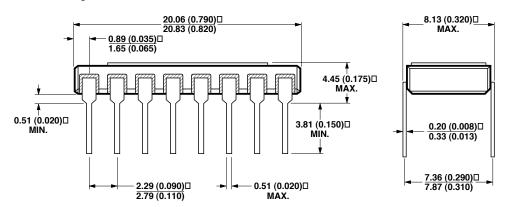
Functional Diagrams

16 Pin DIP Through Hole	8 Pin DIP Through Hole	8 Pin DIP Through Hole
2 Channels	1 Channel	2 Channels
1 16 2 VCC 15 3 V01 14 4 13 5 V02 12 6 11 7 GND 10 8 9	1 V _{CC} 8 2 V _E 7 3 Vout 6 4 GND 5	V _{CC} 8 2

Note: Dual channel devices have common V_{cc} and ground. Single channel DIP has an enable pin 7. All diagrams are "top view."

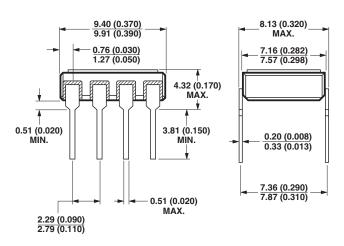
Outline Drawings

16 Pin DIP Through Hole, 2 Channels

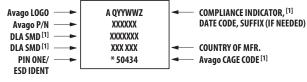


NOTE: DIMENSIONS IN MILLIMETERS (INCHES).

8 Pin DIP Through Hole, 1 and 2 Channels



Device Marking



Note 1. Qualified parts only

NOTE: DIMENSIONS IN MILLIMETERS (INCHES).

Hermetic Optocoupler Options

Option Description 100 Surface mountable hermetic optocoupler with leads trimmed for butt joint assembly. This option is available on standard commercial, class H & class K product in 8 and 16 pin DIP (see drawings below for details). 4.32 (0.170) 0.51 (0.020) MIN. 1.14 (0.045) 1.40 (0.055) 2.29 (0.090) 2.79 (0.110) 0.51 (0.020) MAX. 4.32 (0.170) 0.51 (0.020) MIN. 1.14 (0.045) 1.40 (0.055) 0.20 (0.008) 0.33 (0.013) 0.51 (0.020) MAX. 2.29 (0.090) 2.79 (0.110) 7.36 (0.290) 7.87 (0.310) NOTE: DIMENSIONS IN MILLIMETERS (INCHES). Lead finish is solder dipped rather than gold plated. This option is available on standard commercial, class H 200 and class K products in 8 and 16 pin DIP. DLA Drawing part numbers contain provisions for lead finish. Surface mountable hermetic optocoupler with leads cut and bent for gull wing assembly. This option is avail-300 able on standard commercial, class H & class K product in 8 and 16 pin DIP (see drawings below for details). This option has solder dipped leads. 4.57 (0.180) 0.51 (0.020) 1.40 (0.055) MIN. 1.65 (0.065) 0.51 (0.020) MAX. 4.57 (0.180) 4.57 (0.180) MAX. 0.20 (0.008) 5° MAX. 0.51 (0.020) 1.40 (0.055) 1.07 (0.042) MIN. 1.65 (0.065) 1.32 (0.052) 9.65 (0.380) 9.91 (0.390) 2.29 (0.090) 2.79 (0.110) 0.51 (0.020) MAX. NOTE: DIMENSIONS IN MILLIMETERS (INCHES).

Solder contains lead.

Absolute Maximum Ratings

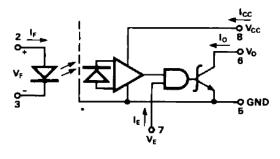
No derating required up to +125°C.

Parameter	Symbol	Min.	Max.	Units
Storage Temperature	T _s	-65	+150	°C
Operating Temperature	T _A	-55	+125	°C
Case Temperature	T _C		+170	°C
Junction Temperature	T _J		+175	°C
Lead Solder Temperature			260 for 10 sec	°C
Peak Forward Input Current (each channel, ≤1 ms duration)	I _{F(PEAK)}		40	mA
Average Input Forward Current (each channel)	I _{F(AVG)}		20	mA
Input Power Dissipation (each channel)			35	mW
Reverse Input Voltage (each channel	V _R		5	V
Supply Voltage (1 minute maximum)	V _{cc}		7.0	V
Output Current (each channel)	I _o		25	mA
Output Voltage (each channel)	V _o		7	V
Output Power Dissipation (each channel)	P _o		40	mW
Package Power Dissipation (each channel)	P _D		200	mW

Single Channel Product Only

Enable Input Voltage	V _E	3.6	V

8 Pin Ceramic DIP Single Channel Schematic



Note enable pin 7. An external 0.01 μF to 0.1 μF bypass capacitor must be connected between V_{cc} and ground for each package type.

ESD Classification

MIL-PRF-38534 and MIL-STD-883, Method 3015

ACPL-560L/01L/0KL, 5962-0824201	(▲B), Class 1B
ACPL-5630L/31L/3KL, 5962-0824202	(▲▲▲A), Class 3A
ACPL-2670L/72L/268KL, 5962-0824203	(▲▲), Class 2

Recommended Operating Conditions

Parameter	Symbol	Min.	Max.	Units
Input Current, Low Level, Each Channel	I _{FL}	0	250	μΑ
Input Current, High Level, Each Channel	I _{FH}	10	20	mA
Supply Voltage, Output	V _{cc}	3.0	3.6	V
Fan Out (TTL Load) Each Channel	N		6	

Recommended Operating Conditions (cont'd.)

Single Channel Product Only^[10]

Parameter	Symbol	Min.	Max.	Units
High Level Enable Voltage	V _{EH}	2.0	V _{cc}	V
Low Level Enable Voltage	V _{EL}	0	0.8	V

Electrical Characteristics ($T_A = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, unless otherwise specified)

				Group		Limits				
Parameter		Symbol	Test Conditions	A ^[13] Sub- groups	Min.	Тур.*	Max.	Units	Fig.	Note
High Leve		I _{OH}	$V_{cc} = 3.3 \text{ V}, V_{o} = 3.3 \text{ V},$ $I_{F} = 250 \mu\text{A}$	1, 2, 3		6	250	μΑ	1	1
Low Leve Output Vo		V _{OL}	$V_{CC} = 3.3 \text{ V, I}_{F} = 10 \text{ mA},$ $I_{OL} \text{ (Sinking)} = 10 \text{ mA}$	1, 2, 3		0.3	0.6	V	2	1, 8
Current Ti Ratio	ransfer	h _F CTR	$V_{o} = 0.6 \text{ V}, I_{F} = 10 \text{ mA},$ $V_{cc} = 3.3 \text{ V}$	1, 2, 3	100			%		1
Logic High	Single Channel	I _{CCH}	$V_{CC} = 3.3 \text{ V, } I_F = 0 \text{ mA}$	1, 2, 3		5	11	mA		1
Supply Current	Dual Channel		$V_{CC} = 3.3 \text{ V},$ $I_{F1} = I_{F2} = 0 \text{ mA}$			10	22	mA		
Logic low	Single Channel	I _{CCL}	$V_{cc} = 3.3 \text{ V},$ $I_{F} = 20 \text{ mA}$	1, 2, 3		6	15	mA		1
Supply Current	Dual Channel		$V_{CC} = 3.3 \text{ V},$ $I_{F1} = I_{F2} = 20 \text{ mA}$			12	30	mA		
Input For	ward	V _F	I _F = 20 mA	1, 2		1.55	1.75	V	3	1
Voltage				3			1.85			
Input Rev Breakdow	erse 'n Voltage	BV _R	$I_R = 10 \mu A$	1, 2, 3	5			V		1
Input-Out Leakage (I _{I-O}	RH \leq 65%, T _A = 25°C t = 5 s, V _{I-O} = 1500 Vdc	1			1.0	μΑ		2, 7
Capacitan Input/ Ou	ce Between tput	C _{I-O}	f = 1 MHz, T _c = 25°C	4		1.0	4.0	pF		1, 3, 13

^{*}All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_{A} = 25 ^{\circ}\text{C}$.

Electrical Characteristics (cont'd) $T_A = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ unless otherwise specified

			Group A ^[13]	Limits					
Parameter	Symbol	Test Conditions	Subgroups	Min.	Typ.*	Max.	Units	Fig.	Note
Propagation Delay	t _{PLH}	$V_{cc} = 3.3 \text{ V, R}_{L} = 510 \Omega,$	9		43	100	ns	4, 5, 6	1, 5
Time to High Output Level		$C_L = 50 \text{ pF, } I_F = 13 \text{ mA}$	10, 11			140			
Propagation Delay	t _{PHL}		9		54	100	ns		
Time to Low Output Level			10, 11			120			
Output Rise Time	t _{LH}	$R_{L} = 510 \Omega, C_{L} = 50 pF,$	9, 10, 11		20	90	ns		1
Output Fall Time	t _{HL}	$I_F = 13 \text{ mA}$			8	40			
Common Mode Transient Immunity at High Output Level	CM _H	$V_{CM} = 50 \text{ V (PEAK)},$ $V_{CC} = 3.3 \text{ V},$ $V_{O} \text{ (min.)} = 2 \text{ V},$ $R_{L} = 510 \Omega, I_{F} = 0 \text{ mA}$	9, 10, 11	1000	>10000		V/µs	7	1, 6, 13
Common Mode Transient Immunity at Low Output Level	CM _L	$V_{CM} = 50 \text{ V (PEAK)},$ $V_{CC} = 3.3 \text{ V},$ $V_{O} \text{ (max.)} = 0.8 \text{ V},$ $R_{L} = 510 \Omega, I_{F} = 10 \text{ mA}$	9, 10, 11	1000	>10000		V/µs	7	1, 6, 13
Single Channel Product	Only								
Low Level Enable Current	I _{EL}	$V_{CC} = 3.3 \text{ V},$ $V_{E} = 0.5 \text{ V}$	1, 2, 3	-2.0	-0.54		mA		
High Level Enable Voltage	V _{EH}		1, 2, 3	2.0			V		9

^{*}All typical values are at $V_{CC} = 3.3 \text{ V}, T_A = 25 ^{\circ}\text{C}.$

Typical Characteristics, $T_A = 25^{\circ}$ C, $V_{cc} = 3.3 \text{ V}$

Parameter	Sym.	Тур.	Units	Test Conditions	Fig.	Note
Input Capacitance	C _{IN}	60	pF	$V_F = 0 \text{ V, } f = 1 \text{ MHz}$		1
Input Diode Temperature Coefficient	ΔV_{F} ΔT_{A}	-1.5	mV/°C	I _F = 20 mA		1
Resistance (Input-Output)	R _{I-O}	1012	Ω	V _{I-O} = 500 V		2

1, 2, 3

8.0

Single Channel Product Only

Low Level Enable Voltage

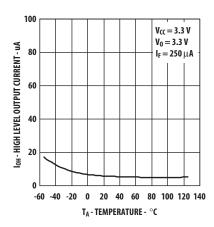
Propagation Delay Time of Enable from V_{EH} to V_{EL}	t _{ELH}	32	ns	$R_L = 510 \Omega, C_L = 50 pF$ $I_F = 13 mA, V_{EH} = 3 V,$	8, 9	1, 10
Propagation Delay Time of Enable from V_{FI} to V_{FH}	t _{EHL}	28	ns	$V_{EL} = 0V$		1, 11

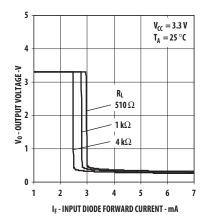
Dual Channel Product Only

Input-Input	I _H	0.5	nA	Relative Humidity ≤ 65%	4
Leakage Current				$V_{I-I} = 500 \text{ V}, t = 5 \text{ s}$	
Resistance (Input-Input)	R _{I-I}	1012	Ω	$V_{I-I} = 500 \text{ V}$	4
Capacitance (Input-Input)	C _{I-I}	0.55	pF	f = 1 MHz	4

Notes:

- 1. Each channel.
- 2. All devices are considered two-terminal devices; I_{LO} is measured between all input leads or terminals shorted together and all output leads or terminals shorted together.
- 3. Measured between each input pair shorted together and all output connections for that channel shorted together.
- 4. Measured between adjacent input pairs shorted together for each multichannel device.
- 5. t_{pHL} propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.5 V point on the leading edge of the output pulse. The t_{pLH} propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.5 V point on the trailing edge of the output pulse.
- 6. CM_L is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state $(V_O < 0.8 \text{ V})$. CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state $(V_O > 2.0 \text{ V})$.
- 7. This is a momentary withstand test, not an operating condition.
- 8. It is essential that a bypass capacitor (0.01 to 0.1 μ F, ceramic) be connected from V_{cc} to ground. Total lead length between both ends of this external capacitor and the isolator connections should not exceed 20 mm.
- 9. No external pull up is required for a high logic state on the enable input.
- 10. The t_{ELH} enable propagation delay is measured from the 1.5 V point on the trailing edge of the enable input pulse to the 1.5 V point on the trailing edge of the output pulse.
- 11. The t_{EHL} enable propagation delay is measured from the 1.5 V point on the leading edge of the enable input pulse to the 1.5 V point on the leading edge of the output pulse.
- 12. Standard commercial parts receive 100% testing at 25°C (Subgroups 1 and 9). Class H and K parts receive 100% testing at 25, 125, and -55°C (Subgroups 1 and 9, 2 and 10, 3 and 11, respectively).
- 13. Parameters are tested as part of device initial characterization and after design and process changes. Parameters are guaranteed to limits specified for all lots not specifically tested.





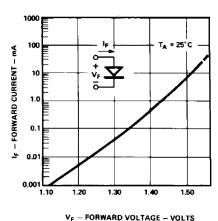
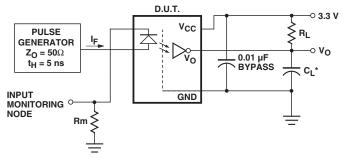


Figure 1. High Level Output Current vs. Temperature.

Figure 2. Input-Output Characteristics.

Figure 3. Input Diode Forward Characteristics.



* CLINCLUDES PROBE AND STRAY WIRING CAPACITANCE.

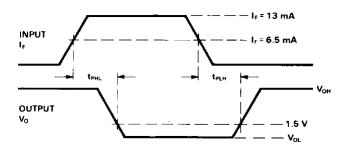


Figure 4. Test Circuit for $t_{\rm PHL}$ and $t_{\rm PLH}$.*

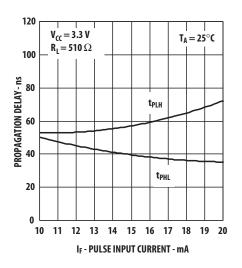


Figure 5. Propagation Delay, $\mathbf{t_{_{PHL}}}$ and $\mathbf{t_{_{PLH}}}$ vs. Pulse Input Current, $\mathbf{I_{_{FH}}}$.

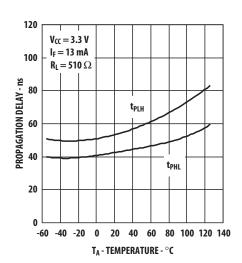


Figure 6. Propagation Delay vs. Temperature.

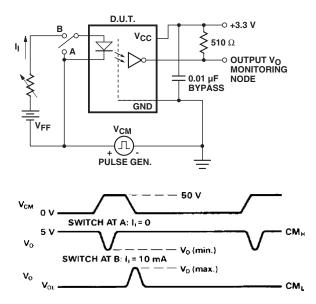


Figure 7. Test Circuit for Common Mode Transient Immunity and Typical Waveforms.

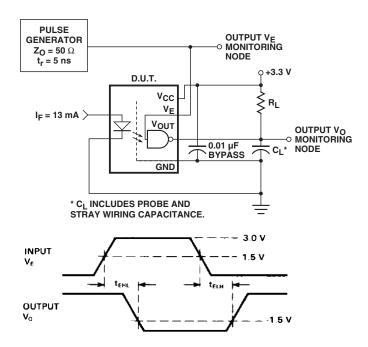


Figure 8. Test Circuit for $\mathbf{t}_{\text{\tiny EHL}}$ and $\mathbf{t}_{\text{\tiny ELH}}.$

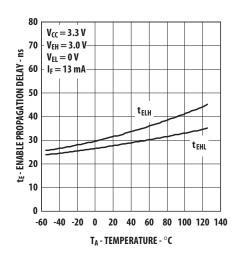
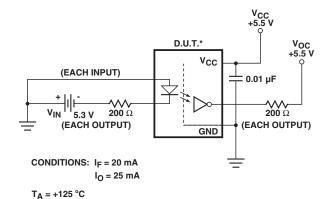


Figure 9. Enable Propagation Delay vs. Temperature.



* ALL CHANNELS TESTED SIMULTANEOUSLY.

Figure 10. Operating Circuit for Burn-In and Steady State Life Tests.

MIL-PRF-38534 Class H, Class K, and DLA SMD Test Program

Avago's Hi-Rel Optocouplers are in compliance with MIL-PRF-38534 Classes H and K. Class H and Class K devices are also in compliance with DLA drawing 5962-08242.

Testing consists of 100% screening and quality conformance inspection to MIL-PRF-38534.

For product information and a complete list of distributors, please go to our website: **www.avagotech.com**

